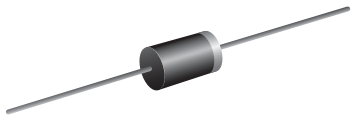
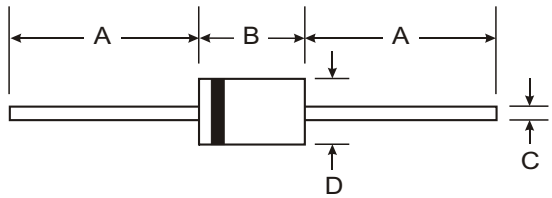
HER501 - HER508

HIGH EFFICIENCY RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V
CURRENT: 5.0 A





Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case: DO-201AD, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number

RoHS COMPLIANT

DO-201AD		
Dim	**Min**	**Max**
A	25.40	—
B	8.50	9.53
C	0.96	1.06
D	4.80	5.21
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	HER 501	HER 502	HER 503	HER 504	HER 505	HER 506	HER 507	HER 508	Unit
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Current 0.375"(9.5mm) Lead Length Ta = 55 °C	$I_{F(AV)}$	5.0								A
Maximum Peak Forward Surge Current, 8.3ms Single half sine wave superimposed on rated load (JEDEC Method)	I_{FSM}	200								A
Maximum Forward Voltage at I_F = 5.0 A	V_F	1.1					1.7			V
Maximum DC Reverse Current Ta = 25 °C	I_R	10								µA
at Rated DC Blocking Voltage Ta = 100 °C	$I_{R(H)}$	50								µA
Maximum Reverse Recovery Time (Note 1)	Trr	50					75			ns
Typical Junction Capacitance (Note 2)	C_J	50								pf
Junction Temperature Range	T_J	- 65 to + 150								°C
Storage Temperature Range	T_{STG}	- 65 to + 150								°C

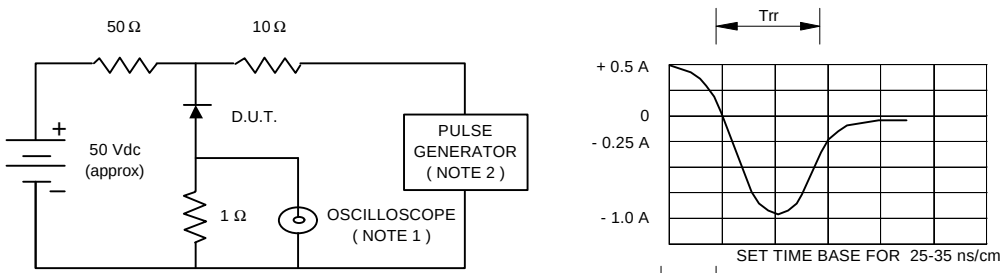
Notes :

(1) Reverse Recovery Test Conditions : I_F = 0.5 A, I_R = 1.0 A, Irr = 0.25 A.

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 V_{DC}

RATING AND CHARACTERISTIC CURVES (HER501 - HER508)

FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES : 1. Rise Time = 7 ns max., Input Impedance = 1 megaohm, 22 pF.
2. Rise time = 10 ns max., Source Impedance = 50 ohms.
3. All Resistors = Non-inductive Types.

FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

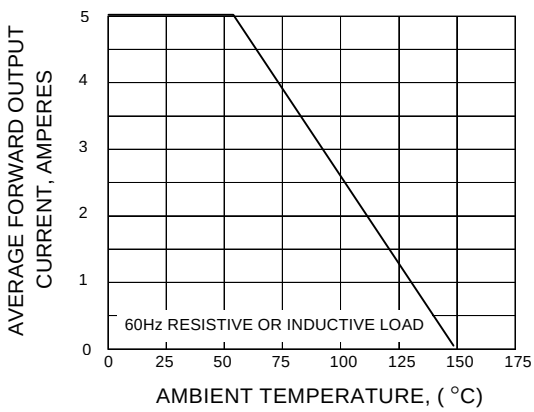


FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

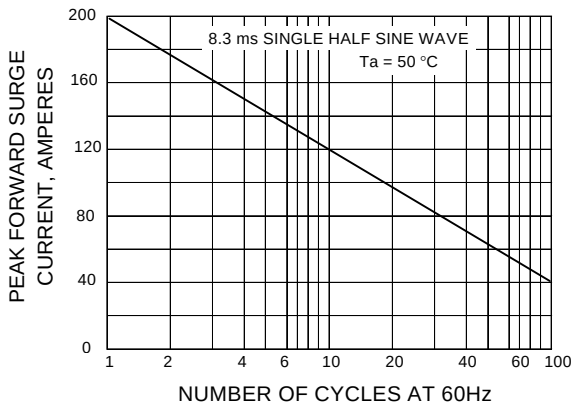


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

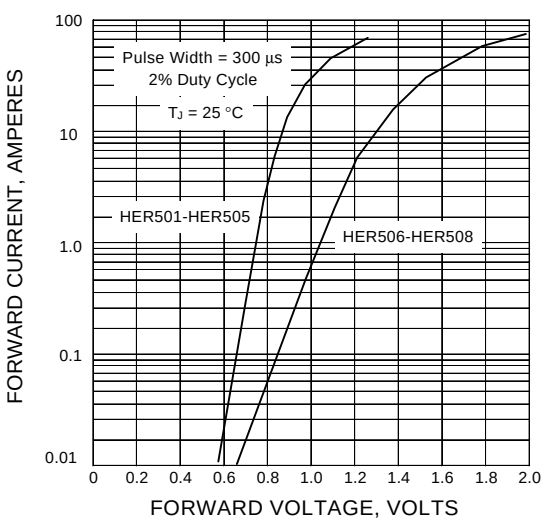


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

